NSN 5961-00-721-3644

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View Online at https://aerobasegroup.com/nsn/5961-00-721-3644 **Inclosure Material:** Metal **Overall Length:** Between 0.300 inches and 0.425 inches Overall Diameter: 0.424 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** Between 0.424 inches and 0.437 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon **Current Rating Per Characteristic:** 2.00 amperes source cutoff current preset **Power Rating Per Characteristic:** 20.0 watts small-signal input power, common-collector blank **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnpn **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Thread Series Designator:** Unf **Terminal Type And Quantity:** 2 tab, solder lug and 1 threaded stud **Specification Data:** 81349-mil-s-19500/372 government specification Shelf Life:

No

N/a

Unit Of Measure:

Demilitarization:

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